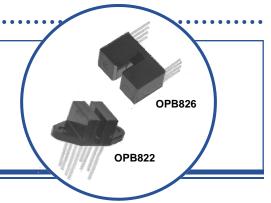
# Dual Channel Encoder OPB822S, OPB822SD OPB826S, OPB826SD



### Features:

- Non-contact switching
- Single or double apertures for high resolution
- · Choice of slot widths
- · Choice of side-by-side or over/under dual channels
- · Choice of electrical outputs



## **Description:**

Each **OPB822** and **OPB826** slotted switch consists of two infrared emitting diodes and two NPN silicon phototransistors mounted on opposite sides of a 0.090" (2.29 mm) wide slot **(OPB822)** or a 0.100" (2.54 mm) wide slot **(OPB826)**.

**OPB822** uses an side-by-side mounting configuration, while **OPB826** uses an over/under mounting configuration. **OPB822S** has 0.01" by 0.04" (0.25 mm x 1.02 mm) apertures in front of both phototransistors while the **OPB822SD** has the aperture in front of both phototransistors and both emitters. The **OPB826S** has 0.04" by 0.04" (1.02 mm x 1.02 mm) apertures in front of both phototransistors while the **OPB826SD** has the aperture in front of both phototransistors and both emitters.

Dual channels enable direction of travel sensing, with the low-cost plastic housing reduces possible interference from ambient light and provides protection from dust and dirt.

Phototransistor switching occurs when an opaque object passes through the device slot.

For information on encoder design, see Application Bulletin 203 at:

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

## **Applications:**

- Encoders
- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety

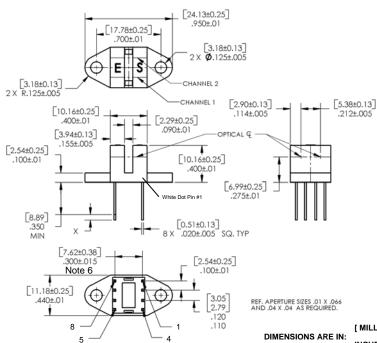
Part Number	LED Peak Wavelength	Sensor	Slot Width / Depth	Aperture Emitter/ Sensor	Lead Length / Spacing
OPB822S	Dual	Dual	0.09" /	None / 0.01"	0.35" /
OPB822SD	935 nm	Transistor	0.30"	0.01" / 0.01"	0.30"
OPB826S	Dual	Dual	0.10" /	NA / 0.04"	0.20" /
OPB826SD	890 nm	Transistor	0.42"	0.04" / 0.04"	0.74"

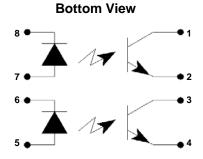


OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.



#### **OPB822**

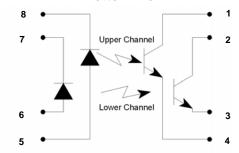




Pin #	Description	Pin#	Description
8	Cathode-1	1	Collector-1
7	Anode-1	2	Emitter-1
6	Cathode-2	3	Collector-2
5	Anode-2	4	Emitter-2

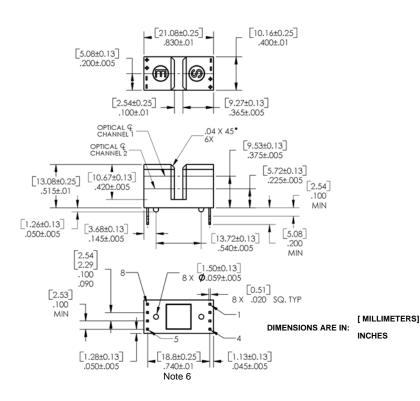
[ MILLIMETERS]

#### **Bottom View**



Pin#	Description	Pin#	Description
8	Cathode-1	1	Collector-1
7	Cathode-2	2	Collector-2
6	Anode-2	3	Emitter-2
5	Anode-1	4	Emitter-1

## **OPB826**



#### **CONTAINS POLYSULFONE**

To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking. Vibra-Tite evaporates fast without causing structural failure in OPTEK's molded plastics.

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# Dual Channel Encoder OPB822S, OPB822SD OPB826S, OPB826SD



## Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +85° C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] <sup>(1)</sup>	240°C

## **Input Diode**

Forward DC Current OPB822S, OPB822SD OPB826S, OPB826SD	50 mA 40 mA
Peak Forward Current (1 μs pulse width, 300 pps)	1 A
Reverse DC Voltage	2 V
Power Dissipation <sup>(2)</sup>	100 mW

#### **Output Phototransistor**

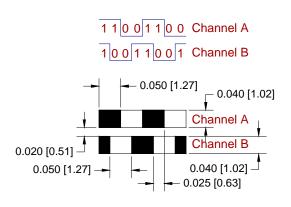
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	30 mA
Power Dissipation <sup>(2)</sup>	100 mW

#### Notes:

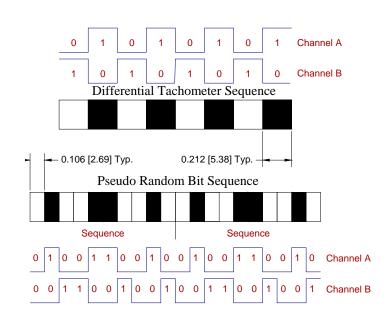
- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/°C above 25° C.
- (3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones. <u>Spray and wipe; do not submerge</u>.
- (4) Derate linearly 3.33 mW/°C above 25° C.
- (5) All parameters tested using pulse techniques.
- (6) Feature controlled at body.

## **Encoder Sequence for OPB822**

## Encoder Sequence for OPB826



For information on encoder design, see Application Bulletin 203 at: http://www.optekinc.com/pdf/App\_Note\_203.pdf



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# **Dual Channel Encoder OPB822S, OPB822SD OPB826S, OPB826SD**



## Electrical Characteristics (OPB822, OPB826) (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
nput Diod	e (see OP14O for OPB822 or OP266 for	OPB82	26 for a	dditiona	l informat	ion)
V <sub>F</sub>	Forward Voltage	-	-	1.7	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	-	100	μA	V <sub>R</sub> = 2 V
Output Ph	ototransistor (see OP550 for OPB822 o	r OP50	6 for O	PB826 f	or additio	nal information)
V <sub>(BR)(CEO)</sub>	Collector-Emitter Breakdown Voltage	30	-	-	V	I <sub>C</sub> = 1 mA
V <sub>(BR)(ECO)</sub>	Emitter-Collector Breakdown Voltage	5	-	-	V	I <sub>E</sub> = 100 μA
I <sub>CEO</sub>	Collector-Emitter Leakage Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$
Coupled		•	•	•		
I <sub>C(ON)</sub>	On-State Collector Current OPB822S OPB822SD OPB826S OPB826SD	250 100 250 100	- - -	- - -	μΑ μΑ μΑ μΑ	$\begin{split} &V_{\text{CE}} = 5 \text{ V, I}_{\text{F}} = 20 \text{ mA} \\ &V_{\text{CE}} = 5 \text{ V, I}_{\text{F}} = 20 \text{ mA} \\ &V_{\text{CE}} = 10 \text{ V, I}_{\text{F}} = 20 \text{ mA} \\ &V_{\text{CE}} = 10 \text{ V, I}_{\text{F}} = 20 \text{ mA} \end{split}$
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage OPB822S OPB822SD OPB826S OPB826SD	- - -	- - -	0.4 0.4 0.4 0.4	V V V	$I_C$ = 125 $\mu$ A, $I_F$ = 20 mA $I_C$ = 50 $\mu$ A, $I_F$ = 20 mA $I_C$ = 125 $\mu$ A, $I_F$ = 20 mA $I_C$ = 50 $\mu$ A, $I_F$ = 20 mA
I <sub>CX1</sub>	Crosstalk OPB822D, OPB822SD OPB826S	-	-	250 20	μA	$I_{F1} = 0 \text{ mA}, I_{F2} = 20 \text{ mA}, V_{CE} = 10$

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#### Notes:

(1) All parameters tested using pulse techniques.

OPB826SD

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